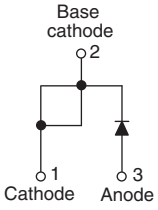
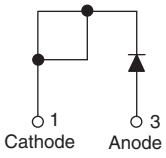
Ultralow V_F Hyperfast Rectifier for Discontinuous Mode PFC, 8 A FRED Pt®

TO-220AC

TO-220 FULL-PAK



VS-8ETL06PbF



VS-8ETL06FPPbF

FEATURES

- Hyperfast recovery time
- Benchmark ultralow forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 pending
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level

Pb-free

e3

RoHS COMPLIANT

DESCRIPTION

State of the art, ultralow V_F, soft-switching hyperfast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W
e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

PRODUCT SUMMARY	
Package	TO-220AC, TO-220FP
$I_{F(AV)}$	8 A
V_R	600 V
V_F at I_F	1.05 V
t_{rr} typ.	60 ns
T_J max.	175 °C
Diode variation	Single die

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Repetitive peak reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$	T_C = 160 °C	8	A
Average rectified forward current, FULL-PAK		T_C = 142 °C		
Non-repetitive peak surge current	I_{FSM}	T_J = 25 °C	175	
Repetitive peak forward current	I_{FM}		16	
Operating junction and storage temperatures	T_J, T_{Stg}		- 65 to 175	°C

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	I_R = 100 µA	600	-	-	V
Forward voltage	V_F	I_F = 8 A	-	0.96	1.05	
		I_F = 8 A, T_J = 150 °C	-	0.81	0.86	
Reverse leakage current	I_R	V_R = V_R rated	-	0.05	5	µA
		T_J = 150 °C, V_R = V_R rated	-	20	100	
Junction capacitance	C_T	V_R = 600 V	-	17	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body	-	8.0	-	nH

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DYNAMIC RECOVERY CHARACTERISTICS (T_C = 25 °C unless otherwise specified)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNITS**
Reverse recovery time	t_{rr}	I_F = 1 A, dI_F/dt = 100 A/µs, V_R = 30 V		-	60	100	ns
		I_F = 8 A, dI_F/dt = 100 A/µs, V_R = 30 V		-	150	250	
		T_J = 25 °C	I_F = 8 A dI_F/dt = 200 A/µs V_R = 390 V	-	170	-	
		T_J = 125 °C		-	250	-	
Peak recovery current	I_{RRM}	T_J = 25 °C		-	15	-	A
		T_J = 125 °C		-	20	-	
Reverse recovery charge	Q_{rr}	T_J = 25 °C		-	1.3	-	µC
		T_J = 125 °C		-	2.6	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNITS**
Maximum junction and storage temperature range	T_J, T_{Stg}		- 65	-	175	°C
Thermal resistance, junction to case	R_{thJC}		-	1.4	2	°C/W
(FULL-PAK)			-	3.4	4.3	
Thermal resistance, junction to ambient per leg	R_{thJA}	Typical socket mount	-	-	70	
Thermal resistance, case to heatsink	R_{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	2.0	-	g
			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-220AC	8ETL06			
		Case style TO-220 FULL-PAK	8ETL06FP			

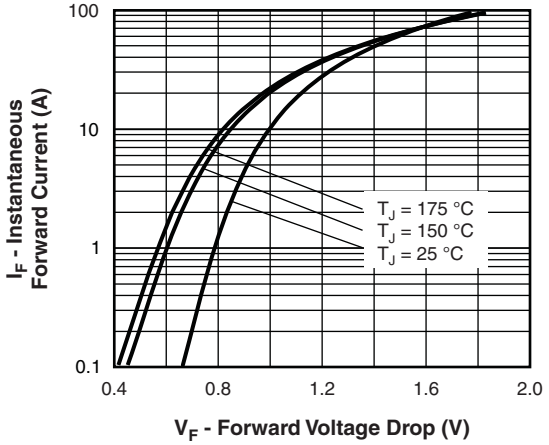

Fig. 1 - Typical Forward Voltage Drop Characteristics

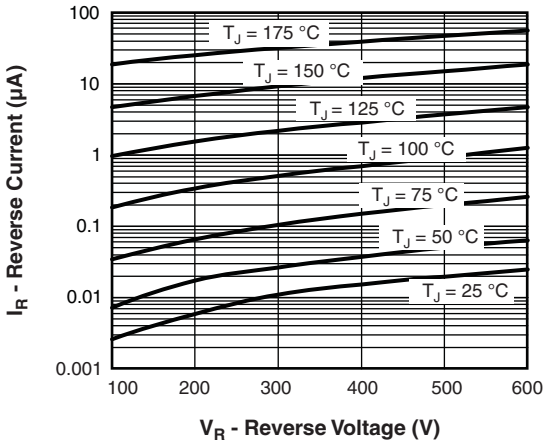

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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Document Number: 94028
Revision: 28-Apr-11

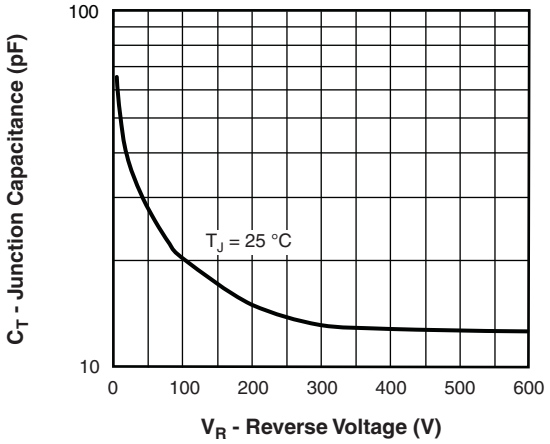

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

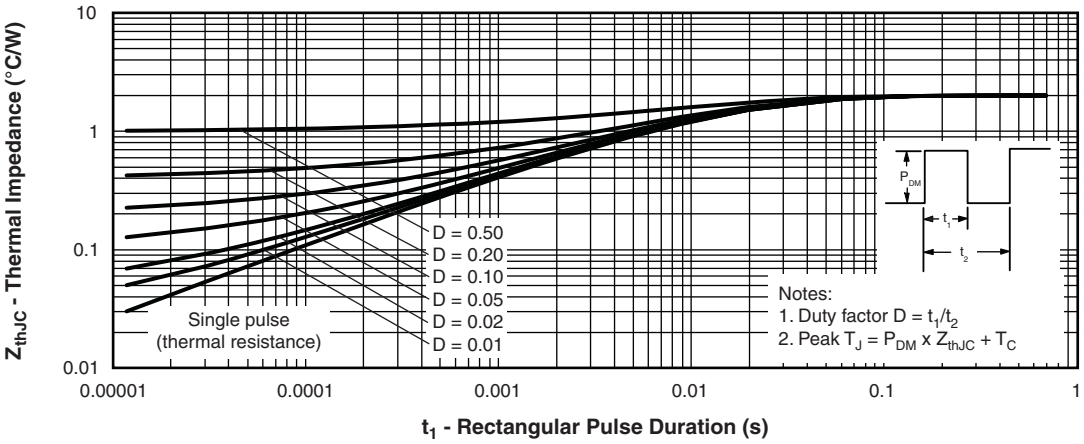

Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

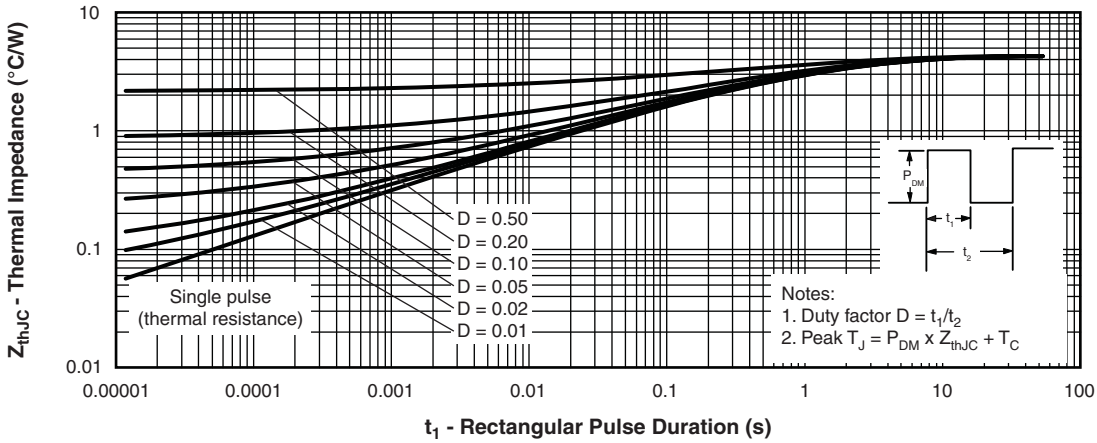

Fig. 5 - Maximum Thermal Impedance Z_{thJC} Characteristics (FULL-PAK)

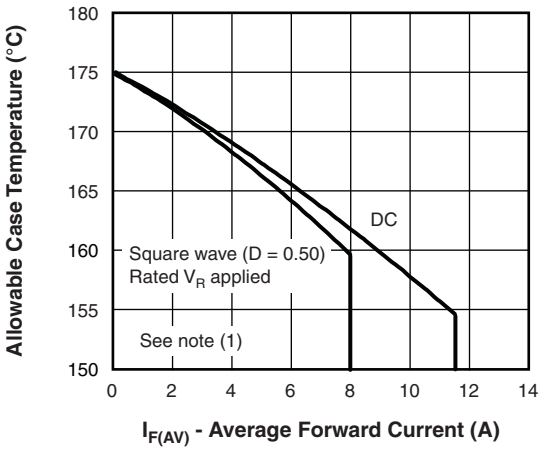

Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

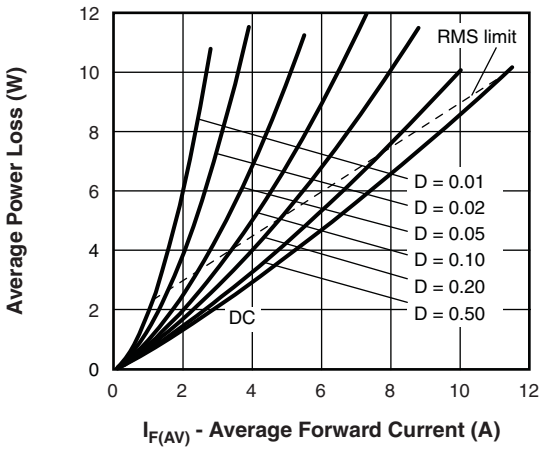

Fig. 8 - Forward Power Loss Characteristics

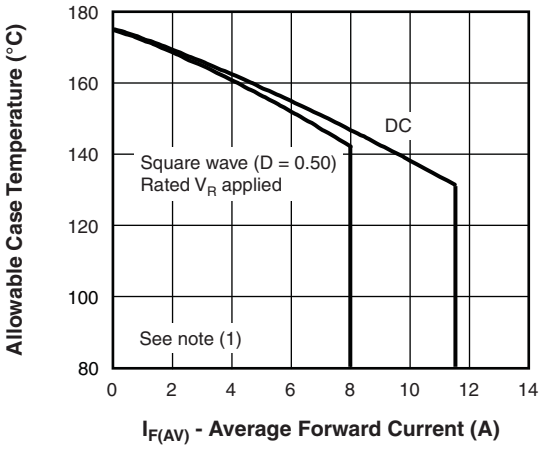

Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

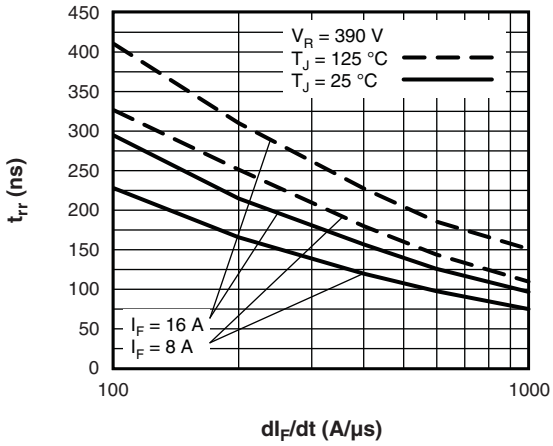

Fig. 9 - Typical Reverse Recovery Time vs. dI_F/dt

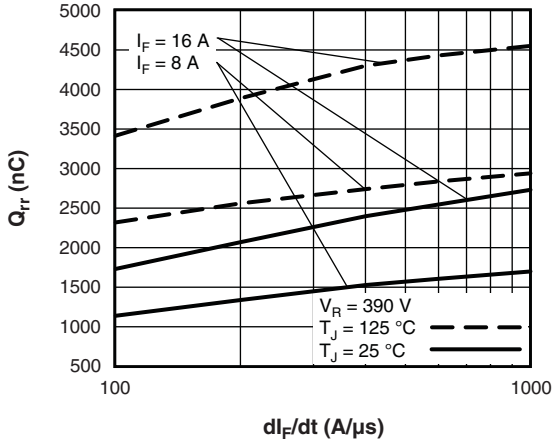

Fig. 10 - Typical Stored Charge vs. dI_F/dt

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 8); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

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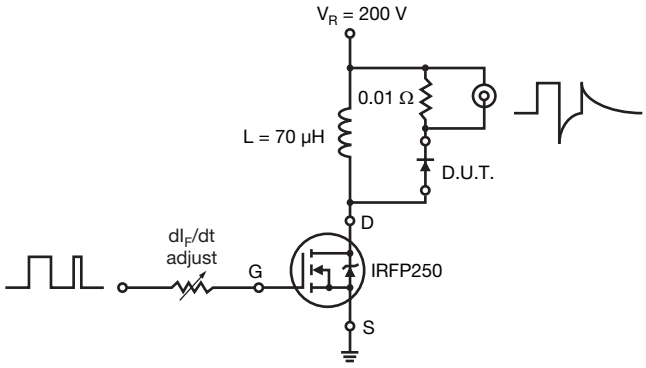
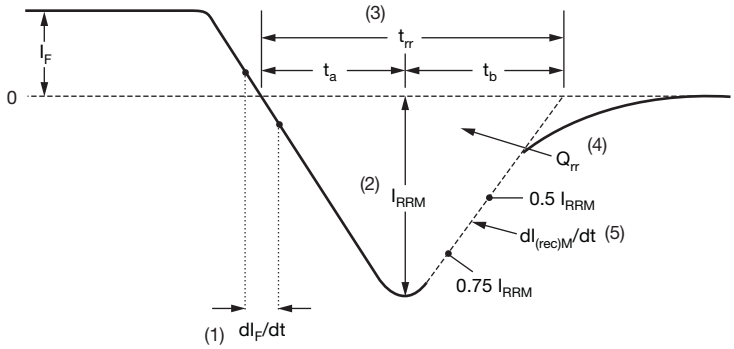


Fig. 11 - Reverse Recovery Parameter Test Circuit



(1) dI_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 12 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code

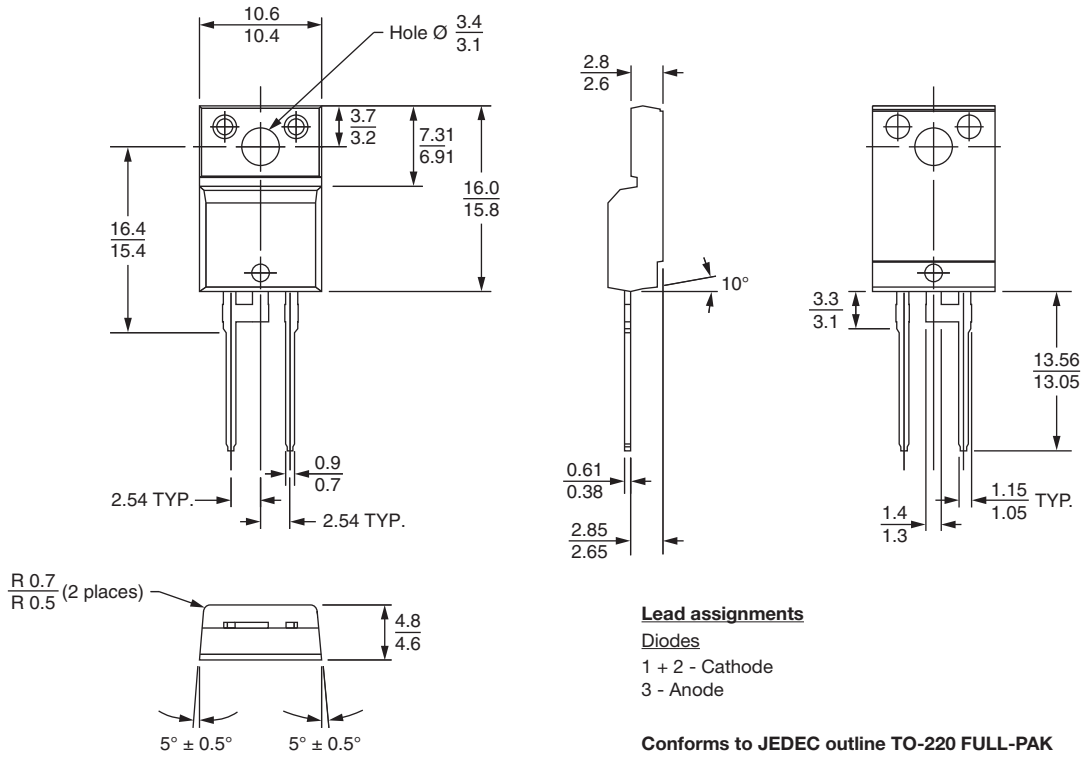
VS-	8	E	T	L	06	FP	PbF
1	2	3	4	5	6	7	8

1	-	Vishay Semiconductors product
2	-	Current rating (8 = 8 A)
3	-	E = Single diode
4	-	T = TO-220, D^2PAK
5	-	L = Ultralow V_F hyperfast recovery
6	-	Voltage rating (06 = 600 V)
7	-	• None = TO-220AC • FP = TO-220 FULL-PAK
8	-	PbF = Lead (Pb)-free

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS		
Dimensions	TO-220AC	www.vishay.com/doc?95221
	TO-220AC FULL-PAK	www.vishay.com/doc?95005
Part marking information	TO-220AC	www.vishay.com/doc?95224
	TO-220AC FULL-PAK	www.vishay.com/doc?95009

DIMENSIONS in millimeters



Lead assignments

Diodes

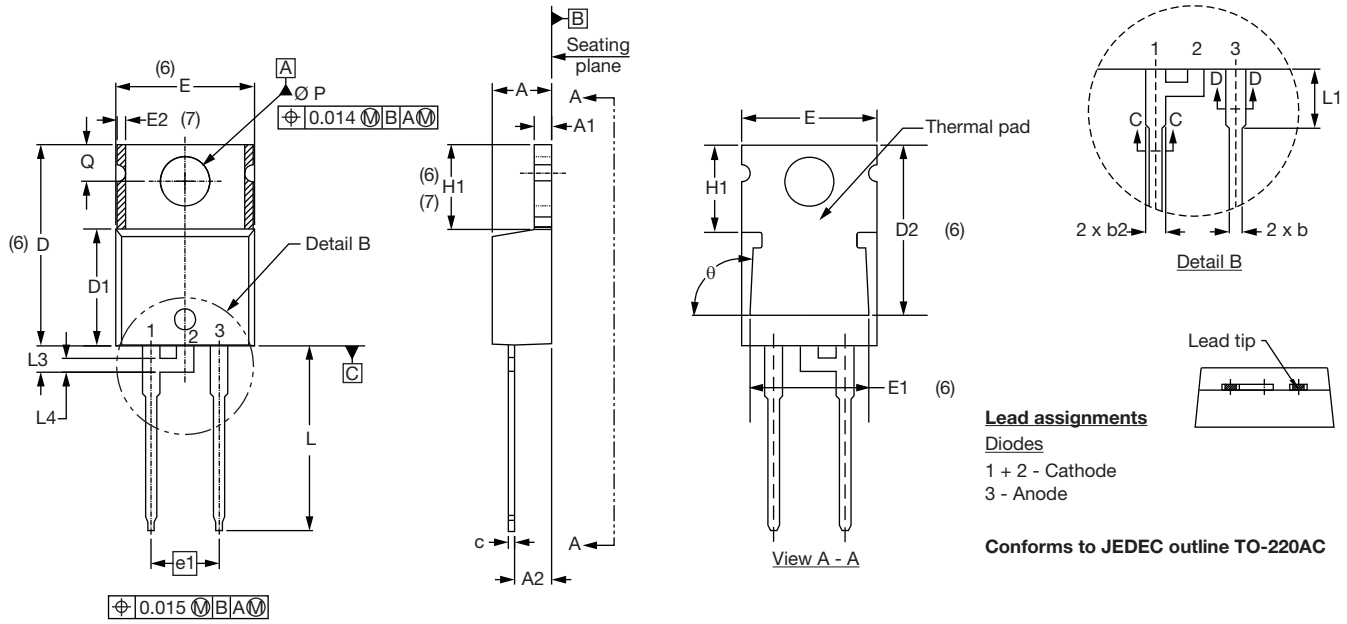
1 + 2 - Cathode

3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK

TO-220AC

DIMENSIONS in millimeters and inches



Lead assignments
Diodes
1 + 2 - Cathode
3 - Anode

Conforms to JEDEC outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
c	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
E	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
e	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
Ø P	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° to 93°		

Notes

(1) Dimensioning and tolerancing as per ASME Y14.5M-1994
(2) Lead dimension and finish uncontrolled in L1
(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
(4) Dimension b1, b3 and c1 apply to base metal only
(5) Controlling dimension: inches
(6) Thermal pad contour optional within dimensions E, H1, D2 and E1
(7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
(8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline

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